TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VHCV573FT,TC74VHCV573FK

Octal Schmitt D-Type Latch with 3-State Output

The TC74VHCV573 is an advanced high speed CMOS OCTAL LATCH with 3-STATE OUTPUT fabricated with silicon gate C2MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

This 8-bit D-type latch is controlled by a latch enable input (LE) and an output enable input (\overline{OE}).

When the \overline{OE} input is high, the eight outputs are in a high impedance state.

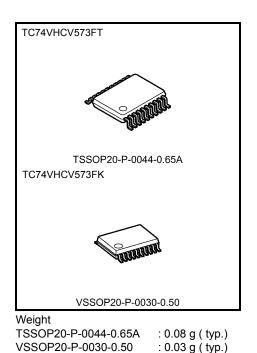
Input pin have hysteresis between the positive-going and negative-going thresholds. Thus the TC74VHCV573 is capable of squaring up transitions of slowly changing input signals and provides an improved noise immunity.

Input protection and output circuit ensure that 0 to 5.5 V can be applied to the input and output (Note) pins without regard to the supply voltage. These structure prevents device destruction due to mismatched supply and input/output voltages such as battery back up, etc.

Note: Output in off-state.

Features

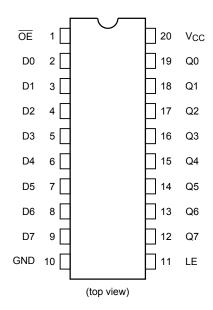
- High speed: $t_{pd} = 5.0 \text{ ns}$ (typ.) at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 2 \mu A (max)$ at $Ta = 25^{\circ}C$
- Wide operating voltage range: V_{CC} (opr) = 1.8 V to 5.5 V
- Ouput current: $|I_{OH}|/I_{OL} = 16 \text{ mA} (\text{min}) (V_{CC} = 4.5 \text{ V})$
- Available in TSSOP and VSSOP (US)
- Power-down protection provided on all inputs and outputs
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 573 type



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Pin Assignment



Truth Table

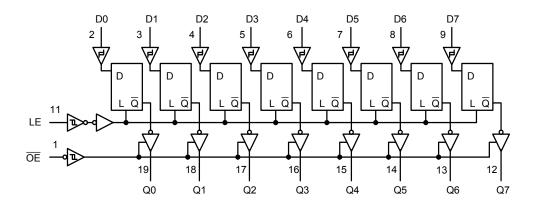
	Inputs	Output			
ŌĒ	LE	D	Output		
Н	Х	Х	Z		
L	L	Х	Q _n		
L	Н	L	L		
L	Н	Н	Н		

X: Don't care

Z: High impedance

 $\mathsf{Q}_{\mathsf{h}}:\mathsf{Q}$ outputs are latched at the time when the LE input is taken to a low logic level.

System Diagram



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	-0.5 to 7.0	V
DC input voltage	V _{IN}	-0.5 to 7.0	V
DC output voltage	Vaur	-0.5 to 7.0 (Note 2)	V
	V _{OUT}	$-0.5 \text{ to } V_{CC} + 0.5 \qquad (\text{Note 3})$	v
Input diode current	Ік	-50	mA
Output diode current	I _{OK}	±50 (Note 4)	mA
DC output current	IOUT	±50	mA
Power dissipation	PD	180	mW
DC V _{CC} /ground current	I _{CC} /I _{GND}	±100	mA
Storage temperature	T _{stg}	-65 to 150	°C

Note1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- Note 2: Output in off-state
- Note 3: High or low state. IOUT absolute maximum rating must be observed.
- Note 4: $V_{OUT} < GND, V_{OUT} > V_{CC}$

Operating Ranges (Note 1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	V _{CC}	1.8 to 5.5	V
Input voltage	VIN	0 to 5.5	V
	V _{OUT}	0 to 5.5 (Note 2)	V
Output voltage		0 to V _{CC} (Note 3)	v
Operating temperature	T _{opr}	-40 to 85	°C
Input rise and fall time	dt/dv	0 to 20(Vcc=3.3 ± 0.3V) 0 to 1(Vcc=5 ± 0.5V)	ms/V

Note 1: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.

Note 2: Output in off-state

Note 3: High or low state.

Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = −40 to 85°C		Unit	
Characteristics	Symbol			V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit
				1.8	_	_	1.65	_	1.65	
				2.3	—	—	1.85	—	1.85	
Positive threshold voltage	VP		—	3.0	—	—	2.20	—	2.20	
				4.5	—	—	3.15	—	3.15	
				5.5	_	—	3.85	—	3.85	v
				1.8	0.15	—	—	0.15	—	v
				2.3	0.45	—	—	0.45	—	
Negative threshold voltage	VN		_	3.0	0.90	—	—	0.90	—	
				4.5	1.35	—	—	1.35	—	
				5.5	1.65	—	—	1.65	—	
	VH	_		1.8	0.15	_	1.05	0.15	1.05	v
				2.3	0.20	_	1.10	0.20	1.10	
Hysteresis voltage				3.0	0.30	_	1.20	0.30	1.20	
				4.5	0.40	_	1.40	0.40	1.40	
				5.5	0.50	—	1.60	0.50	1.60	
	V _{OH}		I _{OH} = -50 μA	1.8	1.7	1.8	_	1.7	_	
		VIN		3.0	2.9	3.0	_	2.9	_	
High-level output voltage		= V _{IH} or		4.5	4.4	4.5	_	4.4	_	
		VIL	I _{OH} = −8 mA	3.0	2.58	—		2.48	—	
			I _{OH} = −16 mA	4.5	3.94	_	_	3.80	_	N
				1.8		0.0	0.1	_	0.1	V
		VIN	I _{OL} = 50 μA	3.0	_	0.0	0.1	_	0.1	
Low-level output voltage	V _{OL}	= V _{IH} or		4.5	_	0.0	0.1	_	0.1	
		VIL	I _{OL} = 8 mA	3.0	_	_	0.36	_	0.44	
			I _{OL} = 16 mA	4.5	_	_	0.44	_	0.55	
3-state output off-state current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 5.5 \text{V}$		1.8 to 5.5	_	_	±0.5	_	±5.0	μA
Power-off leakage current	IOFF	VIN/VOU		0	_	—	0.5	_	5.0	μA
Input leakage current	l _{IN}	$V_{IN} = 5.5 V \text{ or GND}$		0 to 5.5	_	_	±0.1	_	±1.0	μA
Quiescent supply current	ICC	V _{IN} = V _C	_C or GND	5.5	_	_	2.0	—	20.0	μA

Timing Requirements (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition		Ta = 25°C		Ta = -40 to 85°C	Unit
			V _{CC} (V)	Тур.	Limit	Limit	
Minimum pulse width			2.5 ± 0.2	_	6.5	6.5	
(LE)	t _{w (H)}	—	3.3 ± 0.3	—	5.0	5.0	ns
			5.0 ± 0.5	-	5.0	5.0	
			2.5 ± 0.2		5.0	5.0	
Minimum set-up time	ts	—	3.3 ± 0.3	—	3.5	3.5	ns
			5.0 ± 0.5	-	3.5	3.5	
			2.5 ± 0.2		2.0	2.0	
Minimum hold time	t _h	—	3.3 ± 0.3	—	1.5	1.5	ns
			5.0 ± 0.5	_	1.5	1.5	

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AC Characteristics (input: tr = tf = 3 ns)

Characteristics	Symbol	Tes	est Condition		Ta = 25°C			Ta = −40 to 85°C		Unit
	0,11201		V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Min	Max	
			2.5 ± 0.2	15	_	8.9	16.2	1.0	19.0	
			2.5 ± 0.2	50		11.8	19.1	1.0	23.0	
Propagation delay time	t _{pLH}		3.3 ± 0.3	15		6.6	11.9	1.0	14.0	
(LE-Q)	t _{pHL}	—	3.3 ± 0.3	50		8.8	15.4	1.0	17.5	ns
· · /			5.0 ± 0.5	15		5.0	7.7	1.0	9.0	
			5.0 ± 0.5	50		6.6	9.7	1.0	11.0	
			2.5 ± 0.2	15		10.4	15.8	1.0	18.0	
			2.5 ± 0.2	50	_	13.2	20.7	1.0	23.5	
Propagation delay time	t _{pLH}		22102	15		7.5	11.0	1.0	13.0	
(D-Q)	tpHL	_	3.3 ± 0.3	50		9.5	14.5	1.0	16.5	ns
· · ·			5.0 ± 0.5	15		5.4	6.8	1.0	8.0	
				50	_	7.0	8.8	1.0	10.0	
	^t pZL ^t pZH	R _L = 1 kΩ	2.5 ± 0.2	15	_	7.6	16.2	1.0	19.0	ns
				50	_	10.7	19.0	1.0	22.0	
3-state output enable			3.3 ± 0.3	15	_	5.7	11.5	1.0	13.5	
time				50	_	8.1	15.0	1.0	17.0	
			5.0 ± 0.5	15	_	4.2	7.7	1.0	9.0	
				50	_	6.1	9.7	1.0	11.0	
			2.5 ± 0.2	50		13.6	17.3	1.0	19.0	
3-state output disable time	t _{pLZ} t _{pHZ}	R _L = 1 kΩ	3.3 ± 0.3	50	_	10.5	14.5	1.0	16.5	ns
			5.0 ± 0.5	50		8.2	9.7	1.0	11.0	
	4		2.5 ± 0.2	50	_	_	2.0	_	2.0	
Output to output skew	t _{osLH}	(Note 1)	3.3 ± 0.3	50		_	1.5	_	1.5	ns
	t _{osHL}		5.0 ± 0.5	50		_	1.0	—	1.0	
Input capacitance	C _{IN}		_		_	4	10	_	10	pF
Output capacitance	C _{OUT}		_		_	6	_	—	—	pF
Power dissipation capacitance	CPD			(Note 2)	_	25	_	—	—	pF

Note 1: Parameter guaranteed by design.

 $t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|$

Note 2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

ICC (opr) = CPD·VCC·fIN + ICC/8 (per latch)

And the total CPD when n pcs. of latch operate can be gained by the following equation:

C_{PD} (total) = 13 + 12·n

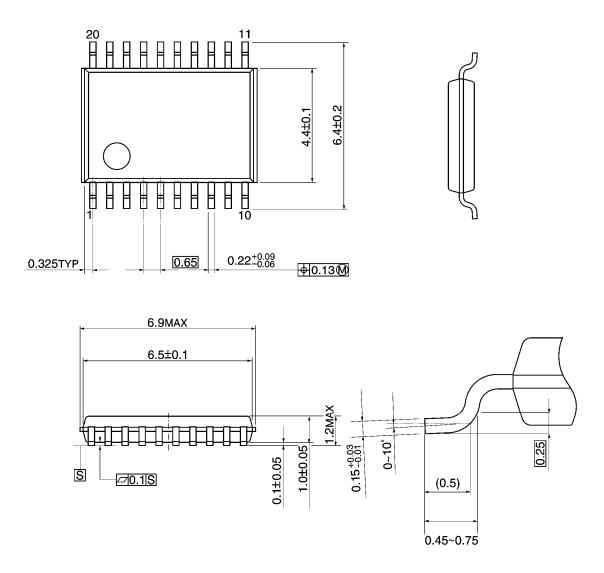
Noise Characteristics (input: t_r = t_f = 3 ns)

Characteristics	Symbol	Test Condition		Ta =	Ta = 25°C	
Characteristics	Symbol		V _{CC} (V)	Тур.	Max	Unit
Quiet output maximum dynamic	Voin	C _L = 50 pF	3.3	0.4	_	V
V _{OL}	V _{OLP}	CL - 50 pr	5.0	0.8	-	v
Quiet output minimum dynamic	V _{OLV}	CL = 50 pF	3.3	-0.1	_	V
V _{OL}			5.0	-0.4	-	v
Minimum high level dynamic input voltage	V _{IHD}	C _L = 50 pF	5.0	-	3.5	V
Maximum low level dynamic input voltage	V _{ILD}	C _L = 50 pF	5.0		1.5	V

Package Dimensions

TSSOP20-P-0044-0.65A

Unit: mm



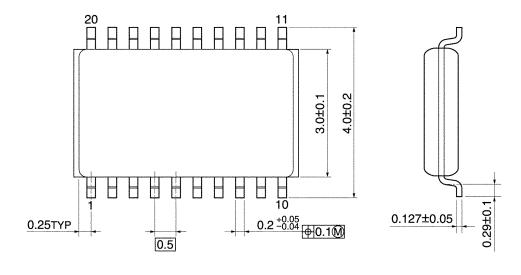
Weight: 0.08 g (typ.)

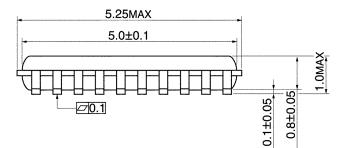
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Package Dimensions

VSSOP20-P-0030-0.50

Unit: mm





Weight: 0.03 g (typ.)

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